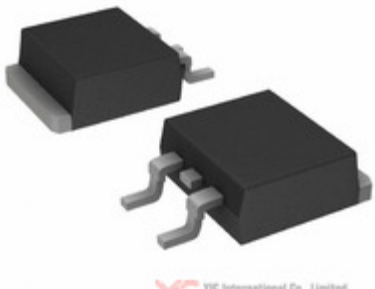

	<p>SUD50N06-07L-GE3</p>
	<p>Hersteller-Teilenummer: SUD50N06-07L-GE3</p>
	<p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p>
	<p>Teil der Beschreibung: MOSFET N-CH 60V 96A DPAK</p>
	<p>Datenblätter:  SUD50N06-07L-GE3.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 27800 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	SUD50N06-07L-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 60V 96A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	27800 pcs Stock
detaillierte Beschreibung	N-Channel 60V 96A (Tc) 136W (Tc) Surface Mount
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	136W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	96A (Tc)
Rds On (Max) @ Id, Vgs	7.4 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	144nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	5800pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SUD50N06-07L-GE3TR

SUD50N06-07L-GE3 ist neu im Original, Suche SUD50N06-07L-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SUD50N06-07L-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SUD50N06-07L-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SUD50N06-08H-E3 Vishay / Siliconix MOSFET N-CH 60V 93A TO252</p>	 <p>SUD50N06 INF INF TO-252</p>	 <p>SUD50N06-08H VISHAY SUD50N06-08H VISHAY</p>	 <p>SUD50N06-09L VISHAY SUD50N06-09L VISHAY</p>
 <p>SUD50N06-09L-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 60V 50A TO252</p>	 <p>SUD50N06-07L VISHAY SUD50N06-07L VISHAY</p>	 <p>SUD50N06-07L-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 60V 96A TO252</p>	 <p>SUD50N06-07L-E3 Vishay / Siliconix MOSFET N-CH 60V 96A TO252</p>

heiße Teile

Mehr

- | | | | | |
|--------------------|----------------------|----------------------|------------------------|-----------------------|
| ⊛ SUD50N04-05L-E3 | ↔ SUD50N04-06H | ⇒ SUD50N04-06P | D SUD50N04-07 | ⇒ SUD50N04-07-T4-GE3 |
| ⊣ SUD50N04-07L | ⊛ SUD50N04-07L-E3 | D SUD50N04-09H | ⇒ SUD50N04-09H-E3 | ⇒ SUD50N04-09H-E3 |
| ⊛ SUD50N04-09L-E3 | ⊣ SUD50N04-10P-E3 | ⊛ SUD50N04-13P | ↔ SUD50N04-13P-E3 | ⇒ SUD50N04-16P |
| D SUD50N04-25P | ⊛ SUD50N04-37P | ⊣ SUD50N04-37P-E3 | ⊛ SUD50N04-37P-E3-4GE3 | ⇒ SUD50N04-37P-T4-GE3 |
| ⇒ SUD50N04-8M8P | ↔ SUD50N04-8M8P-4GE3 | ⊛ SUD50N04-8M8P-4GE3 | ⊣ SUD50N04-8M8P-E3 | ⇒ SUD50N06-07L |
| ↔ SUD50N06-07L-GE3 | ⇒ SUD50N06-08H | D SUD50N06-09L | ⊛ SUD50N06-09L-E3 | ⊣ SUD50N06-09L-E3 |
| ⊛ SUD50N06-16 | D SUD50N06-36 | ⇒ SUD50N06L-09 | ↔ SUD50N10-18P | ⇒ SUD50N10-18P-E3 |
| ⊣ SUD50N10-18P-E3 | ⊛ SUD50N10-18P-T4-E3 | ↔ SUD50N10-34P | ⇒ SUD50NP04-62-4-E3 | ⇒ SUD50NP04-62-T4-E3 |
| ⊛ SUD50NP04-77P | ⊣ SUD50P04-08 | ⊛ SUD50P04-08-GE3 | D SUD50P04-08-GE3 | ⇒ SUD50P04-08L |
| ↔ SUD50P04-09L | ⊛ SUD50P04-09L-E3 | ⊣ SUD50P04-09L-E3 | ⊛ SUD50P04-09L-GE3 | ⇒ SUD50P04-13L-E3 |

Contact us:Info@Y-IC.com

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